

# Moh Adhib Ulil Absor

## List of Publications by Year in descending order

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Version: 2024-02-01

27  
papers

372  
citations

840119

11  
h-index

794141

19  
g-index

27  
all docs

27  
docs citations

27  
times ranked

419  
citing authors

#	ARTICLE	IF	CITATIONS
1	Strain-controlled spin splitting in the conduction band of monolayer $WS_2$ Physical Review B, 2016, 94. Intrinsic persistent spin helix state in two-dimensional group-IV monochalcogenide $MX_2$		
2			

#	ARTICLE	IF	CITATIONS
19	Effect of external electric field on spin-orbit splitting of the two-dimensional tungsten dichalcogenides $WX_2$ ( $X = S, Se$ ). Journal of Physics: Conference Series, 2018, 1011, 012070.	0.3	4
20	Electronics Structure of Monochalcogenide Materials MX (M = Ge, Sn and Pb; X = S and Se) Buckled Square Lattice. IOP Conference Series: Materials Science and Engineering, 0, 515, 012105.	0.3	3
21	Layer dependence of electronic structure in SnSe using first principle study. Materials Today: Proceedings, 2021, 44, 3249-3252.	0.9	1
22	Polarity Effect on the Electronic Structure of Molybdenum Dichalcogenides $MoXY$ (X, Y = S, Se): A Computational Study Based on Density-Functional Theory. Indonesian Journal of Chemistry, 2021, 21, 598.	0.3	1
23	Quantum Size level Structure of Colloidal CdTe Quantum Dot Nanocrystal : A Multi-band Approach. , 2009, , .		0
24	K-space Orientation Dependent of the Spin Texture in $SF_3PbI_3$ Perovskite Compounds. IOP Conference Series: Materials Science and Engineering, 2019, 515, 012060.	0.3	0
25	The impact of preferential orientations of organic cation on the spin textures of hybrid organic-inorganic perovskite $CH_3NH_3PbX_3$ (X = Br, Cl). Materials Today: Proceedings, 2021, 44, 3273-3276.	0.9	0
26	Effect of Thin Film Thickness on the Electronic Properties of Wurtzite Structure (ZnO and GaN): A Density Functional Theory Study. Key Engineering Materials, 0, 884, 394-404.	0.4	0
27	Rashba Effect on Buckled Square Lattice Ge and Sn chalcogenides (MX, M=Ge,Sn, X=O,S,Se,Te) using DFT method. Indonesian Journal of Chemistry, 2020, 20, 697.	0.3	0